Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	("6595506").PN.	US-PGPUB; USPAT	OR	OFF	2006/06/27 07:58
L11	0	(118/715-733.cds. 156/345.\$.cds.) and (quasam)	US-PGPUB; USPAT	OR	ON	2006/06/27 08:12
L12	0	(quasam) same suppport\$3 same (substrate semiconductor wafer workpiece)	US-PGPUB; USPAT	OR	ON	2006/06/27 08:13
L13	4	(quasam)	US-PGPUB; USPAT	OR	ON	2006/06/27 08:21
L14	1	10/247,999	US-PGPUB; USPAT	OR	ON	2006/06/27 08:21
L15	2	10/247,499	US-PGPUB; USPAT	OR	ON	2006/06/27 08:21
L23	9	("5952060").URPN.	USPAT	OR	ON	2006/06/27 08:30
L24	37	("4340462" "4491496" "4534816" "4612077" "4948458" "5006200" "5022979" "5200232" "5262029" "5268200" "5308661" "5365585" "5393572" "5494713" "5522932" "5569356" "5641375" "5680013" "5798016" "5812362" "5820723" "5824605" "5838529" "5846613" "589536" "5879523" "5885356" "5888907" "5891253" "5895586" "5904778" "5916370" "5952060" "5989511" "6015597" "6048798" "6071828").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/06/27 08:34
L25	1	24 and (dylyn din)	US-PGPUB; USPAT; USOCR	OR	ON	2006/06/27 08:34
L26	11	("6015597").URPN.	USPAT	OR	ON	2006/06/27 08:35
	75	(US-20030047283-\$ or US-20050183669-\$ or US-20050252454-\$ or US-20060075969-\$ or US-20050045106-\$ or US-20040244695-\$ or US-20040055709-\$ or US-20030069632-\$ or US-20040018749-\$ or US-20030168168-\$ or US-20050022746-\$ or US-20030162314-\$ or US-20050163985-\$).did. or (US-6228471-\$ or US-5352493-\$ or US-6508911-\$ or US-5508071-\$ or US-6579833-\$ or US-5695565-\$ or US-5507874-\$ or US-5638251-\$ or US-H000566-\$ or US-5786068-\$ or US-5728465-\$ or US-6998636-\$ or US-6472062-\$ or US-6200675-\$ or US-6998636-\$ or US-669996-\$ or US-648642-\$ or US-6699199-\$ or US-648642-\$ or US-5718976-\$ or US-5758548-\$ or US-5718976-\$ or US-57595648-\$ or US-5718976-\$ or US-57595648-\$ or US-6135054-\$ or US-6595506-\$ or US-649729-\$ or US-6135054-\$ or US-5935323-\$ or US-5812362-\$ or US-6537429-\$ or US-5166856-\$ or US-5952060-\$ or US-6537429-\$ or US-6015597-\$ or US-6551718-\$ or US-5820723-\$ or US-5846613-\$ or US-5989511-\$).did. or (WO-9712757-\$ or WO-9640446-\$ or WO-9639943-\$ or WO-2005054539-\$ or WO-9740207-\$).did. or (JP-01167211-\$ or JP-2002246455-\$ or JP-06348154-\$ or JP-06025856-\$).did. or (DE-1004004177-\$ or WO-2005054540-\$ or US-5352493-\$ or JP-01167211-\$ or US-5786068-\$ or EP-856592-\$ or JP-10096082-\$).did.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/06/27 08:44
L28	21	27 and titanium	US-PGPUB; USPAT	OR	ON	2006/06/27 09:01
L29	0	"2004055709"	US-PGPUB; USPAT	OR	ON	2006/06/27 09:01

		EAST Scarciffise				
L30	1	"20040055709"	US-PGPUB; USPAT	OR	ON ·	2006/06/27 09:42
L31	26	parkhe-vijay.in. ahmann-kurt.in. tsai-matthew.in. sansoni-steve.in.	US-PGPUB; USPAT	OR	ON	2006/06/27 09:42
S 7	6	(("6493629") or ("6340928") or ("6674403") or ("5977913") or ("6850735") or ("6714605")).PN.	US-PGPUB; USPAT	OR	OFF	2006/06/13 20:32
S8	3	(("5354381") or ("5572038") or ("5911832")).PN.	US-PGPUB; USPAT	OR	OFF	2006/03/23 16:23
S9	1	("6747464").PN.	US-PGPUB; USPAT	OR	OFF	2006/03/23 16:23
S10	0	(118/715-733.ccls. 156/345.\$.ccls.) and (carbon same diamond same network same suppport\$3)	US-PGPUB; USPAT	OR	ON	2006/06/13 21:17
S11	0	((carbon with hydrogen with network) same suppport\$3 same (substrate semiconductor wafer workpiece))	US-PGPUB; USPAT	OR	ON	2006/06/13 20:35
S12	0	((carbon with hydrogen with network) same suppport\$3 same (substrate semiconductor wafer workpiece))	EPO; JPO; DERWENT	OR	ON	2006/06/13 20:35
S13	0	((carbon with hydrogen) same suppport\$3 same (substrate semiconductor wafer workpiece))	EPO; JPO; DERWENT	OR	ON	2006/06/13 20:34
S14	0	((carbon with hydrogen) same suppport\$3 same (substrate semiconductor wafer workpiece))	US-PGPUB; USPAT	OR	ON	2006/06/27 08:13
S15	801	((carbon with hydrogen) same support\$3 same (substrate semiconductor wafer workpiece))	US-PGPUB; USPAT	OR	ON	2006/06/13 20:34
S16	2	(118/715-733.ccls. 156/345.\$.ccls.) and (carbon same diamond same network same support\$3)	US-PGPUB; USPAT	OR	ON	2006/06/13 20:43
S17	2	((carbon with hydrogen with network) same support\$3 same (substrate semiconductor wafer workpiece))	US-PGPUB; USPAT	OR	ON	2006/06/13 20:35
S18	2	((carbon with hydrogen with network) same support\$3 same (substrate semiconductor wafer workpiece))	EPO; JPO; DERWENT	OR∴ =	ON	2006/06/13 20:35
S19	801	((carbon with hydrogen) same support\$3 same (substrate semiconductor wafer workpiece))	US-PGPUB; USPAT	OR	ON	2006/06/13 20:48
S20	39	(diamond same (carbon with hydrogen) same support\$3 same (substrate semiconductor wafer workpiece))	US-PGPUB; USPAT	OR	ON	2006/06/13 20:36
S21	2	S20 and nanocomposite	US-PGPUB; USPAT	OR	ON	2006/06/13 20:36
S22	8	S15 and nanocomposite	US-PGPUB; USPAT	OR	ON	2006/06/13 20:36
S23	36	(118/715-733.ccls. 156/345.\$.ccls.) and (carbon same diamond same support\$3)	US-PGPUB; USPAT	OR	ON	2006/06/13 20:43
S24	3	((carbon with hydrogen) same support\$3 same (substrate semiconductor wafer workpiece) same friction same hardness)	US-PGPUB; USPAT	OR	ON	2006/06/13 20:46
S25	1	((carbon with hydrogen) same support\$3 same (substrate semiconductor wafer workpiece) same friction same hardness)	EPO; JPO; DERWENT	OR	ON	2006/06/13 20:46
S26	1	((carbon with hydrogen) same support\$3 same friction same hardness)	EPO; JPO; DERWENT	OR	ON	2006/06/13 20:46
S27	2	((carbon with diamond) same support\$3 same friction same hardness)	EPO; JPO; DERWENT	OR	ON	2006/06/13 20:46
S28	44	((carbon same hydrogen same silicon same oxygen) same support\$3 same (substrate semiconductor wafer workpiece))	US-PGPUB; USPAT	OR	ON	2006/06/13 20:48
S29	1	((carbon same hydrogen same silicon same oxygen same composite) same support\$3 same (substrate semiconductor wafer workpiece))	US-PGPUB; USPAT	OR	ON	2006/06/13 20:48
S30	6	S28 and diamond	US-PGPUB; USPAT	OR	ON	2006/06/13 20:48
S31	0	("2003/0047283").URPN.	USPAT	OR	ON	2006/06/13 21:00

S32	636	bekaert	US-PGPUB; USPAT	OR	ON	2006/06/13 21:00
S33	40	bekaert and (diamond)	US-PGPUB; USPAT	OR	ON	2006/06/13 21:00
S34	40	bekaert and (diamond diamond\$1like)	US-PGPUB; USPAT	OR	ON	2006/06/13 21:01
S35	2	("6200675").URPN.	USPAT	OR	ON	2006/06/13 21:03
S36	0	("6669996").URPN.	USPAT	OR	ON	2006/06/13 21:04
S37	0	("6669996").URPN.	USPAT	OR	ON	2006/06/13 21:04
S38	2	("6200675").URPN.	USPAT	OR	ON	2006/06/13 21:04
S39	0	(118/715-733.ccls. 156/345.\$.ccls.) and (cdylyn)	US-PGPUB; USPAT	OR	ON	2006/06/13 21:08
S40	0	(118/715-733.ccls. 156/345.\$.ccls.) and (dylyn)	US-PGPUB; USPAT	OR	ON	2006/06/13 21:08
S41	31	(dylyn)	US-PGPUB; USPAT	OR	ON	2006/06/13 21:08
S42	0	(118/715-733.cds. 156/345.\$.cds.) and (S41)	US-PGPUB; USPAT	OR	ON	2006/06/13 21:08
S43	7	(\$41) and (support\$3 with (substrate semiconductor wafer workpiece))	US-PGPUB; USPAT	OR	ON	2006/06/13 21:09
S44	0	(delryn) and (support\$3 with (substrate semiconductor wafer workpiece))	EPO; JPO; DERWENT	OR	ON	2006/06/13 21:09
S45	0	(dylyn) and (support\$3 with (substrate semiconductor wafer workpiece))	EPO; JPO; DERWENT	OR	ON	2006/06/13 21:10
S46	. 0	(dln) and (support\$3 with (substrate semiconductor wafer workpiece))	EPO; JPO; DERWENT	OR	ON	2006/06/13 21:11
S47	0	(belaert) and (support\$3 with (substrate semiconductor wafer: workpiece))	EPO; JPO; DERWENT	OR ·	ON	2006/06/13 21:11
S48	2	(bekaert) and (support\$3 with (substrate semiconductor wafer workpiece))	EPO; JPO; DERWENT	OR	ON	2006/06/13 21:11
S49	420	(118/715-733.ccls. 156/345.\$.ccls.) and (carbon same (diamond diamond\$1like) suppport\$3)	US-PGPUB; USPAT	OR	ON	2006/06/13 21:17
S50	9617	(118/715-733.ccls. 156/345.\$.ccls.) and (carbon same (diamond diamond\$1like) support\$3)	US-PGPUB; USPAT	OR	ON	2006/06/13 21:17
S51	36	(118/715-733.cds. 156/345.\$.cds.) and (carbon same (diamond diamond\$1like)same support\$3)	US-PGPUB; USPAT	OR	ON	2006/06/13 21:18
S52	1034	(shield\$3 lin\$3) with (provid\$3 cover\$3 protect\$3) with (bottom) with chamber	US-PGPUB; USPAT	OR	ON	2006/06/14 09:21
S53	70	(118/715-733.ccls. 156/345.\$.ccls.) and ((shield\$3 lin\$3) with (provid\$3 cover\$3 protect\$3) with (bottom) with chamber)	US-PGPUB; USPAT	OR	ON	2006/06/14 09:21
S54	55	(118/715-733.ccls. 156/345.\$.ccls.) and ((shield shielding liner) with (provid\$3 cover\$3 protect\$3) with (bottom) with chamber)	US-PGPUB; USPAT	OR	ON	2006/06/14 09:31
S55	9	(118/715-733.ccls. 156/345. \pm .ccls.) and ((inner \pm 1chamber sub \pm 1chamber) with (liner shield))	US-PGPUB; USPAT	OR	ON	2006/06/14 09:32
S56	2	(("5352493") or ("5466431")).PN.	US-PGPUB; USPAT	OR	OFF	2006/06/15 17:46
S57	44	("5466431").URPN.	USPAT	OR	ON	2006/06/15 17:48
S58	9	S57 and susceptor	US-PGPUB; USPAT	OR	ON	2006/06/15 17:49
S59	0	dln with susceptor	US-PGPUB; USPAT	OR	ON	2006/06/15 17:49
S60	0	dln with susceptor	EPO; JPO; DERWENT	OR	ON	2006/06/15 17:49

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3	dln and (118/728-732.cds. 156/345.51-345.54.cds.)	US-PGPUB; USPAT	OR	ON	2006/06/15 17:51
961	dln	US-PGPUB; USPAT	OR	ON	2006/06/15 17:50
3	dln and (118/728-732.cds. 156/345.51-345.55.cds.)	US-PGPUB; USPAT	OR	ON	2006/06/15 18:01
178	dln and ((substrate wafer semiconductor substrate) same (support\$4 hold\$4 table susceptor))	US-PGPUB; USPAT	OR	ON	2006/06/15 17:53
123	dln and ((substrate wafer semiconductor substrate) with (support\$4 hold\$4 table susceptor))	US-PGPUB; USPAT	OR	ON	2006/06/15 17:52
9	dln same((substrate wafer semiconductor substrate) with (support\$4 hold\$4 table susceptor))	US-PGPUB; USPAT	OR	ON	2006/06/15 17:52
0	dln and ((substrate wafer semiconductor substrate) same (support\$4 hold\$4 table susceptor))	EPO; JPO; DERWENT	OR	ON	2006/06/15 18:20
0	dln and ((substrate wafer semiconductor substrate) and (support\$4 hold\$4 table susceptor))	EPO; JPO; DERWENT	OR	ON	2006/06/15 17:54
2	din and ((support\$4 hold\$4 table susceptor))	EPO; JPO; DERWENT	OR	ON	2006/06/15 17:54
7	diamond and nanocomposite and ((support\$4 hold\$4 table susceptor))	EPO; JPO; DERWENT	OR	ON	2006/06/15 17:56
17	diamond and nanocomposite and (substrate wafer)	EPO; JPO; DERWENT	OR	ON	2006/06/15 17:56
5	(diamond\$5 with carbon with \$5composite) and (118/728-732. ccls. 156/345.51-345.55.ccls.)	US-PGPUB; USPAT	OR	ON	2006/06/15 18:00
6	(diamond\$5 with carbon with \$5composite) and (susceptor)	US-PGPUB; USPAT	OR	ON	2006/06/15 18:00
83	(diamond same carbon) and (118/728-732.cds. 156/345. 51-345.55.cds.)	US-PGPUB; USPAT	OR	ON	2006/06/15 18:24
70	(diamond with carbon) and (118/728-732.ccls. 156/345. 51-345.55.ccls.)	US-PGPUB; USPAT	OR	ON	2006/06/15 18:14
7	"269"/\$.ccls. and (diamond with carbon)	US-PGPUB; USPAT	OR	ON	2006/06/15 18:15
5	("6595506").URPN.	USPAT	OR	ON	2006/06/15 18:16
0	("6595506").URPN. and diamond	USPAT	OR	ON	2006/06/15 18:16
0	("6595506").URPN. and diamond\$5	USPAT	OR	ON	2006/06/15 18:16
0	S77 and diamond\$5	USPAT	OR	ON	2006/06/15 18:16
12	("5166856" "5324012" "5583736" "5707409" "5812362" "5924917" "5935323" "5989693" "6086796" "6135054" "6256187" "6316734").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/06/15 18:17
2	"01167211"	EPO; JPO; DERWENT	OR:	ON	2006/06/15 18:20
305	(diamond\$5 with carbon) and ((substrate wafer semiconductor substrate) same (support\$4 hold\$4 table susceptor))	EPO; JPO; DERWENT	OR	ON	2006/06/15 18:24
283	(diamond\$5 with carbon) and ((substrate wafer semiconductor substrate) with (support\$4 hold\$4 table susceptor))	EPO; JPO; DERWENT	OR	ON	2006/06/15 18:25
170	(diamond\$5 with carbon) same ((substrate wafer semiconductor substrate) with (support\$4 hold\$4 table susceptor))	EPO; JPO; DERWENT	OR	ON	2006/06/15 18:25
68	("diamond-like" with carbon) same ((substrate wafer semiconductor substrate) with (support\$4 hold\$4 table susceptor))	EPO; JPO; DERWENT	OR	ON	2006/06/15 18:25
72	(diamond\$1like with carbon) same ((substrate wafer semiconductor substrate) with (support\$4 hold\$4 table susceptor))	EPO; JPO; DERWENT	OR	ON	2006/06/15 18:37
	961 3 178 123 9 0 0 2 7 17 5 6 83 70 7 5 0 0 12 2 305 283 170 68	dln and (118/728-732.ccls. 156/345.51-345.55.ccls.) dln and ((substrate wafer semiconductor substrate) same (support\$4 hold\$4 table susceptor)) dln and ((substrate wafer semiconductor substrate) with (support\$4 hold\$4 table susceptor)) dln same((substrate wafer semiconductor substrate) with (support\$4 hold\$4 table susceptor)) dln and ((substrate wafer semiconductor substrate) same (support\$4 hold\$4 table susceptor)) dln and ((substrate wafer semiconductor substrate) and (support\$4 hold\$4 table susceptor)) dln and ((support\$4 hold\$4 table susceptor)) dlamond and nanocomposite and ((support\$4 hold\$4 table susceptor)) diamond and nanocomposite and ((support\$4 hold\$4 table susceptor)) diamond and nanocomposite and (substrate wafer) (diamond\$5 with carbon with \$5composite) and (118/728-732.ccls. 156/345.51-345.55.cds.) (diamond same carbon) and (118/728-732.ccls. 156/345. 51-345.55.cds.) (diamond with carbon) and (118/728-732.ccls. 156/345. 51-345.55.cds.) (diamond with carbon) and (118/728-732.ccls. 156/345. 51-345.55.cds.) ("6595506").URPN. ("6595506").URPN. and diamond ("6135054" "6256187" "5383736" "5707409" "5812362" "5924917" "5932322" "5989693" "6086796" "6135054" "6256187" diamond\$5 with carbon) and ((substrate wafer semiconductor substrate) with (support\$4 hold\$4 table susceptor)) (diamond\$5 with carbon) and ((substrate wafer semiconductor substrate) with (support\$4 hold\$4 table susceptor)) (diamond-like" with carbon) same ((substrate wafer semiconductor substrate) with (support\$4 hold\$4 table susceptor)) ("diamond-like" with carbon) same ((substrate wafer semiconductor substrate) with (support\$4 hold\$4 table susceptor))	SPAT	US-PGPUB US-P	USPAT US-PGPUB; USPAT USPAT OR ON USPAT USPAT OR ON USPAT OR O

S88	35	(diamond\$1like with carbon) same ((substrate wafer semiconductor substrate) with (support\$4 hold\$4 table susceptor chuck electrostatic "esc" clamp)) same (protect\$4 prohibit\$4 wear resist\$4 hard\$4 friction\$4 elas\$7 abras\$5)	EPO; JPO; DERWENT	OR	ON	2006/06/15 18:28
S89	1	("5952060").PN.	US-PGPUB; USPAT	OR	OFF	2006/06/15 18:34
S90	1	(diamond\$1like with carbon with nano\$1composite) and electrostatic	EPO; JPO; DERWENT	OR	ON	2006/06/15 18:38
S91	6	(diamond\$1like with carbon with nano\$1composite) and electrostatic	US-PGPUB; USPAT	OR	ON	2006/06/15 18:39
S92	9	(diamond\$1like with nano\$1composite) and electrostatic	US-PGPUB; USPAT	OR	ON	2006/06/15 18:41
S93	10	(diamond\$1like with nano\$1composite) and electrostatic\$5	US-PGPUB; USPAT	OR	ON	2006/06/15 18:41
S94	1	S93 not S92	US-PGPUB; USPAT	OR	ON	2006/06/15 18:41
S95	1	(diamond\$1like with nano\$1composite) and electrostatic\$5	EPO; JPO; DERWENT	OR	ON	2006/06/15 18:42
S96	5	"856592"	EPO; JPO; DERWENT	OR	ON	2006/06/15 18:42
S97	2	(("5352493") or ("6228471")).PN.	US-PGPUB; USPAT	OR	OFF	2006/06/26 17:00
S98	1	("20030047283").PN.	US-PGPUB; USPAT	OR	OFF	2006/06/26 17:00